



# JT05N065RED/VED/SED/FED

## 主要参数 MAIN CHARACTERISTICS

$I_c$	5 A
$V_{CES}$	650V
$V_{cesat-typ}$ (@ $V_{ge}=15V$ )	1.5V

### 用途

- 逆变器
- UPS 电源

### APPLICATIONS

- General purpose inverters
- UPS

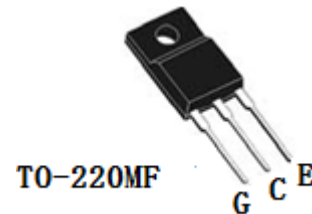
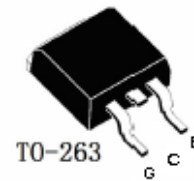
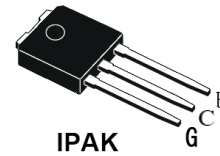
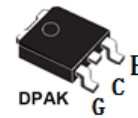
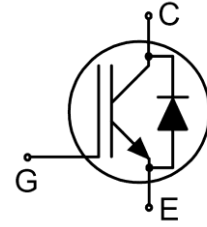
### 产品特性

- 低栅极电荷
- Trench FS 技术,
- 通态压降,  $V_{CE(sat)}$ , typ = 1.5V @  $I_c = 5A$  and  $T_c = 25^\circ C$
- RoHS 产品

### FEATURES

- Low gate charge
- Trench FS Technology,
- saturation voltage:  $V_{CE(sat)}$ , typ = 1.5V @  $I_c = 5A$  and  $T_c = 25^\circ C$
- RoHS product

## 封装 Package



## 订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Non halogen-Tube	有卤-编带 Halogen-Reel	无卤-编带 Non halogen-Reel		
JT05N065RED-R-B	JT05N065RED-R-BR	JT05N065RED-R-A	JT05N065RED-R-AR	JT05N065RED	DPAK
JT05N065VED-V-B	JT05N065VED-V-BR	JT05N065VED-V-A	N/A	JT05N065VED	IPAK
JT05N065SED-S-B	JT05N065SED-S-BR	JT05N065SED-S-A	JT05N065SED-S-AR	JT05N065SED	TO-263
JT05N065FED-F-B	JT05N065FED-F-BR	N/A	N/A	JT05N065FED	TO-220MF



绝对最大额定值 ABSOLUTE RATINGS ( $T_C=25^\circ\text{C}$ )

项 目 Parameter	符 号 Symbol	数 值 Value			单 位 Unit
		JT05N065 RED/VED	JT05N065SED	JT05N065FED	
最高集电极—发射极直流 电压 Collector-Emmitter Voltage	$V_{CES}$	650	650	650	V
*连续集电极电流 Collector Current-continuous	$I_C$ $T=25^\circ\text{C}$ $T=100^\circ\text{C}$	10	10	10	A
		5	5	5	A
最大脉冲集电极极电流（注 1） Collector Current – pulse (note 1)	$I_{CM}$	20	20	20	A
最高栅极发射极电压 Gate-Emmitter Voltage	$V_{GES}$	$\pm 20$	$\pm 20$	$\pm 20$	V
Turn-off safe area	-	20	20	20	A
耗散功率 Power Dissipation	$P_D$ $T_C=25^\circ\text{C}$	56.8	96.2	25	W
最高结温及存储温度 Operating and Storage Temperature Range	$T_J, T_{STG}$	$-55\sim+150$	$-55\sim+150$	$-55\sim+150$	$^\circ\text{C}$
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	$T_L$	300	300	300	$^\circ\text{C}$

\*连续集电极电流由最高结温限制

\*Collector current limited by maximum junction temperature





## 电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
<b>关态特性 Off –Characteristics</b>						
集电极-发射极击穿电压 Collector-Emmitter Voltage	$BV_{CES}$	$I_C=500\mu A, V_{GE}=0V$	650	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{CES}/\Delta T_J$	$I_C=1mA$ , referenced to $25^\circ C$	-	0.5	-	$V/^\circ C$
零栅压下集电极漏电流 Zero Gate Voltage Collector Current	$I_{CES}$	$V_{CE}=650V, V_{GE}=0V, T_C=25^\circ C$	-	-	10	$\mu A$
正向栅极体漏电流 Gate-body leakage current, forward	$I_{GESF}$	$V_{CE}=0V, V_{GE}=20V$	-	-	200	nA
反向栅极体漏电流 Gate-body leakage current, reverse	$I_{GESR}$	$V_{CE}=0V, V_{GE}=-20V$	-	-	-200	nA
<b>通态特性 On-Characteristics</b>						
阈值电压 Gate Threshold Voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}, I_C=250\mu A$	4.5	-	6.5	V
饱和压降 Collector-Emmitter saturation Voltage	$V_{CESAT}$	$V_{GE}=15V, I_C=5A$ $T_C=25^\circ C$	-	1.5	1.8	V
<b>动态特性 Dynamic Characteristics</b>						
输入电容 Input capacitance	$C_{ies}$	$V_{CE}=25V,$ $V_{GE}=0V,$ $f=1.0MHz$	-	259	-	pF
输出电容 Output capacitance	$C_{oes}$		-	31.3	-	pF
反向传输电容 Reverse transfer capacitance	$C_{res}$		-	10.3	-	pF
栅极电荷总量 Total Gate Charge	$Q_g$	$V_{CC}=480V, I_C=5A, V_{GE}=15V$ $T_C=25^\circ C$ (note 2)	-	13.7	-	nC
栅极-发射极 Gate to emitter charge	$Q_{ge}$		-	5.8	-	
栅极-集电极 Gate to collector charge	$Q_{gc}$		-	2.3	-	
栅极电阻-Gate resistance	$R_g$	$f=1MHz$ , open collector	-	2.0	-	$\Omega$
短路电流-short current	$I_{SC}$	$V_{GE}=15V, V_{CE}=400V$	-	40	-	A





## 电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
开启延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{CC}=400V, I_c=5A, R_G=60\Omega$ $V_{GE}=15V$ $T_C=25^\circ C$ (note 3)	-	22	-	ns
上升时间 Turn-On rise time	$t_r$		-	15	-	ns
关断延迟时间 Turn-Off delay time	$t_{d(off)}$		-	104	-	ns
下降时间 Turn-Off Fall time	$t_f$		-	32	-	ns
开通损耗 Turn-On energy	$E_{on}$		-	132	-	$\mu J$
关断损耗 Turn-off energy	$E_{off}$		-	65	-	$\mu J$
总开关损耗 Total switching energy	$E_{tot}$		-	197	-	$\mu J$
反并联二极管特性及最大额定值 Anti-Parallel Diode Characteristics and Maximum Ratings						
正向压降 Drain-Source Diode Forward Voltage	$V_F$	$V_{GE}=0V, I_S=2.5A$	-	1.5	1.8	V
反向恢复时间 Diode Reverse recovery time	$t_{rr}$	$V_{GE}=0V, V_R=400V, I_F=5A$ $di_F/dt=200A/\mu s$	-	70	-	ns
反向恢复电荷 Diode Reverse recovery charge	$Q_{rr}$		-	145	-	nC
反向恢复电流 Diode Reverse recovery Current	$I_{RRM}$		-	4.0	-	A

项 目 Parameter	符 号 Symbol	典型 Typ			单 位 Unit
		JT05N065 RED/VED	JT05N065SED	JT05N065FED	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	2.2	1.8	5	$^\circ C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	110	62	65	$^\circ C/W$

注释:

- 1: 脉冲宽度由最高结温限制
- 2: 基本与工作温度无关
- 3: 脉冲测试: 脉冲宽度 $\leq 300\mu s$ , 占空比 $\leq 2\%$

Notes:

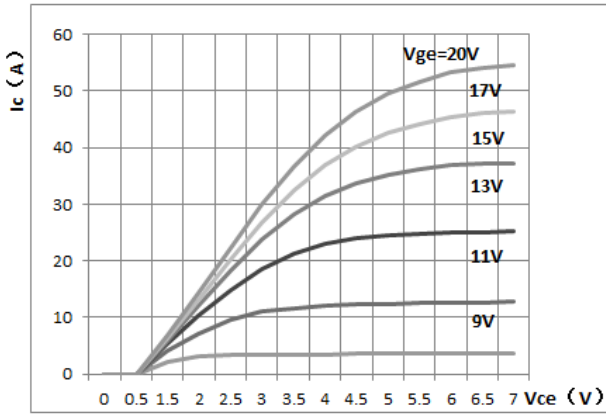
- 1: Pulse width limited by maximum junction temperature
- 2: Essentially independent of operating temperature
- 3: Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycles  $\leq 2\%$



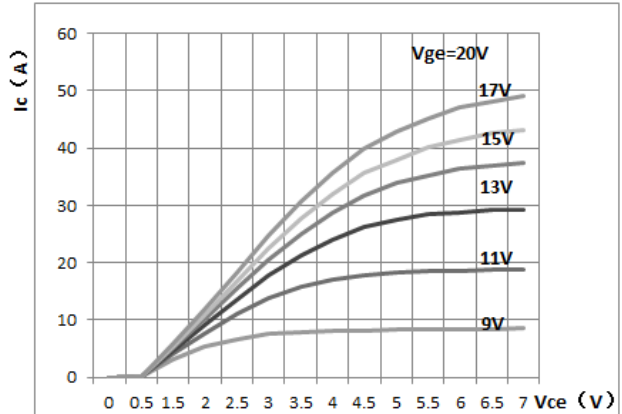


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

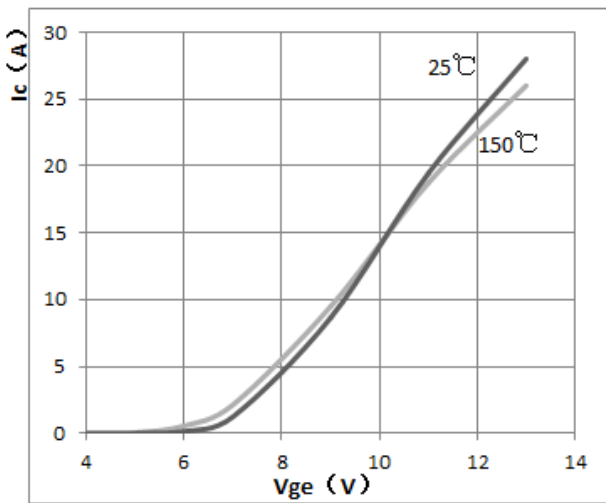
Output Characteristics  $T_j=25^\circ\text{C}$



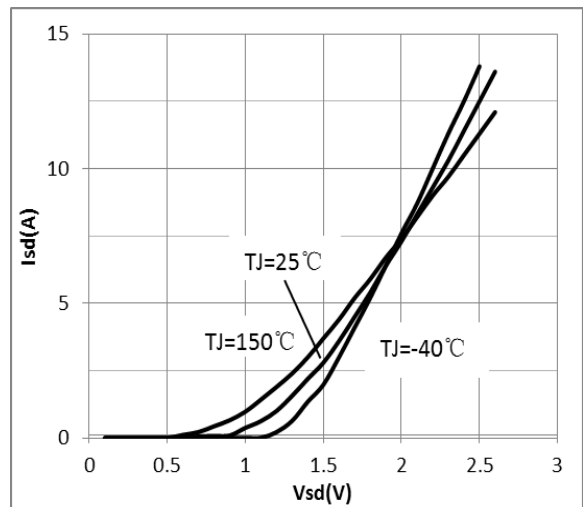
Output Characteristics  $150^\circ\text{C}$



Transfer Characteristics

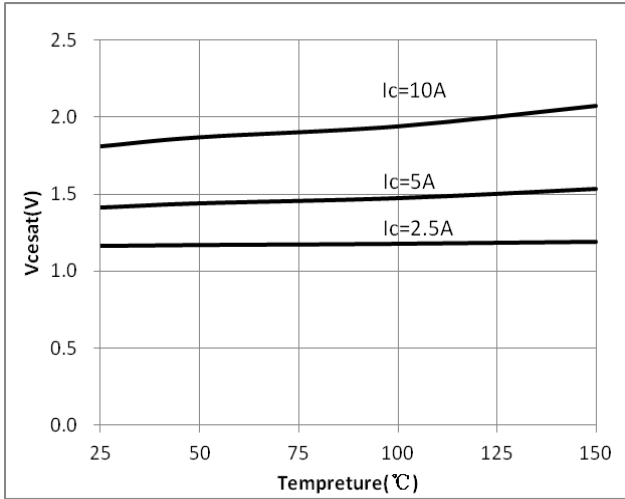


Diode Characteristic



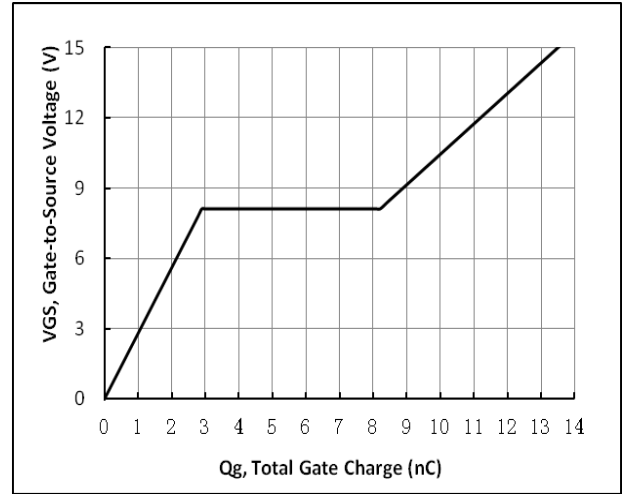


Collector-Emitter Saturation Voltage vs Tj



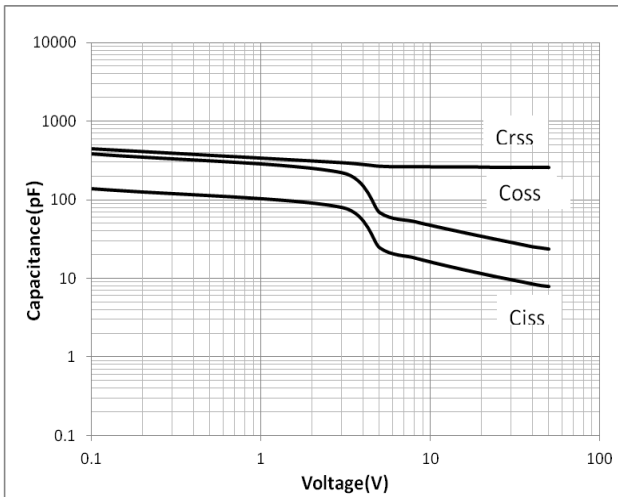
Gate-charge Characteristics

Vce=480V, Ic=5A, VGE=15V



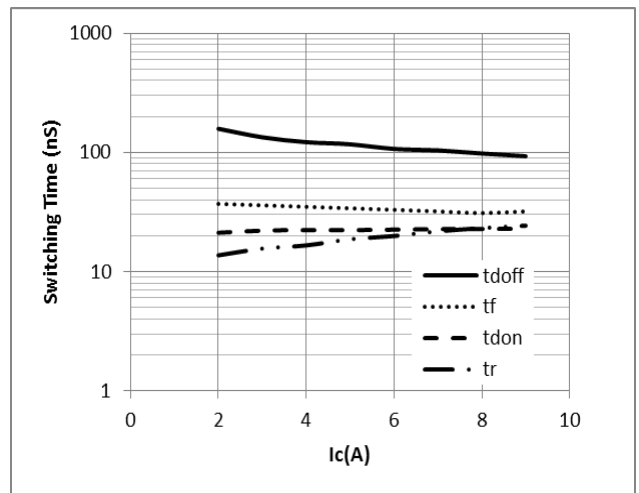
Capacitance Characteristic

Vce=25V, VGE=0V, f=1.0MHz



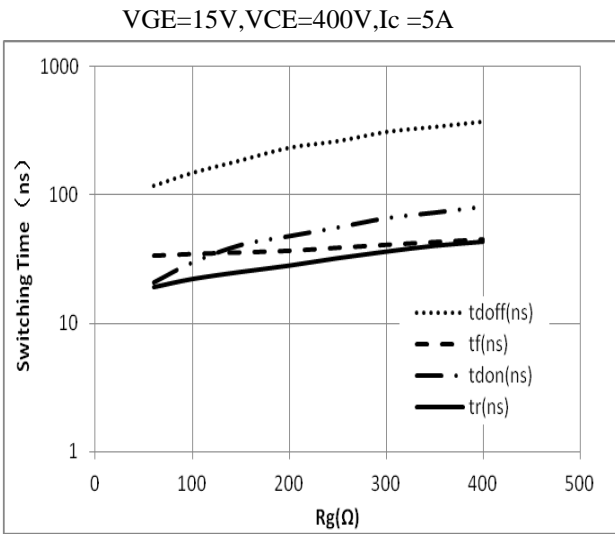
Switching Time vs. IC (Tj=150°C)

VGE=15V, VCE=400V, Rg=60Ω

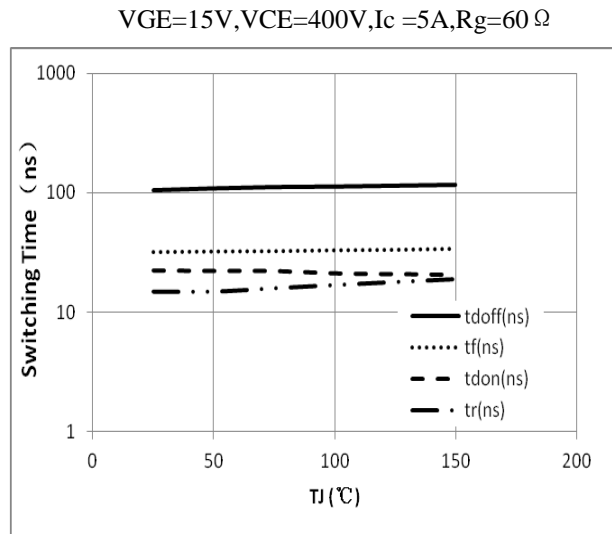




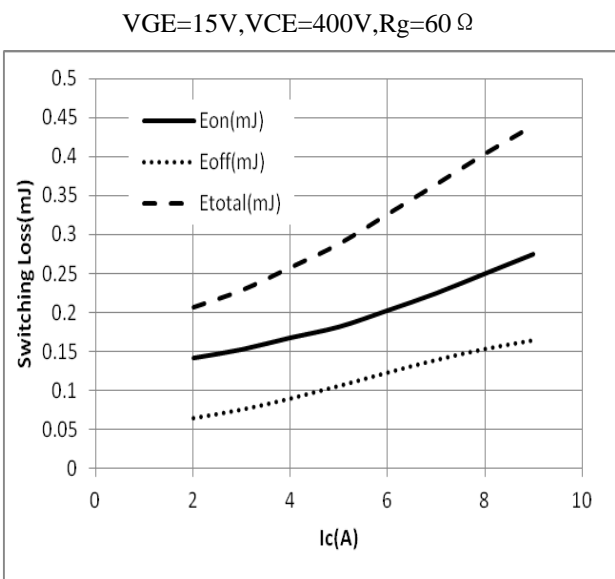
Switching Time vs.Rg(Tj=150°C)



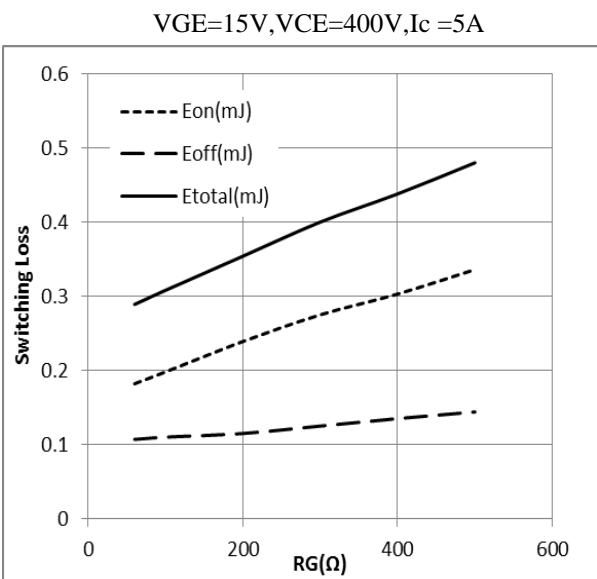
Switching Time vs.Tj



Switching Loss vs. Ic (Tj=150°C)



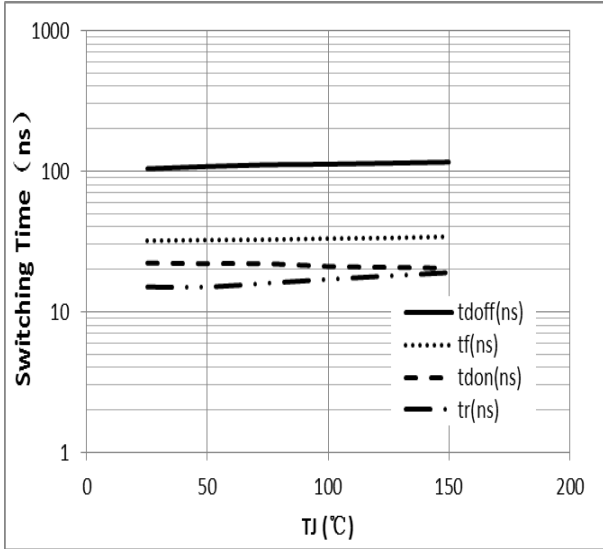
Switching Loss vs. Rg (Tj=150°C)





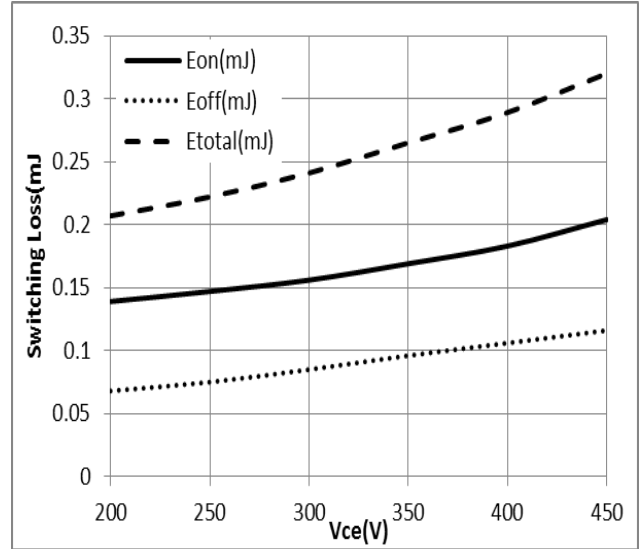
Switching Loss vs. Tj

VGE=15V, VCE=400V, Ic =5A, Rg=60 Ω

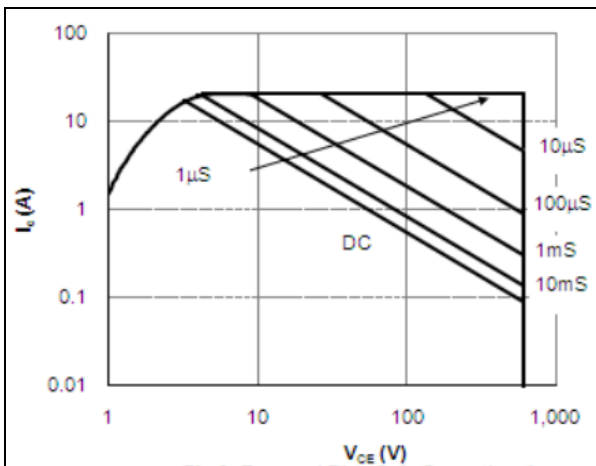


Switching Loss vs. Vce (Tj=150°C)

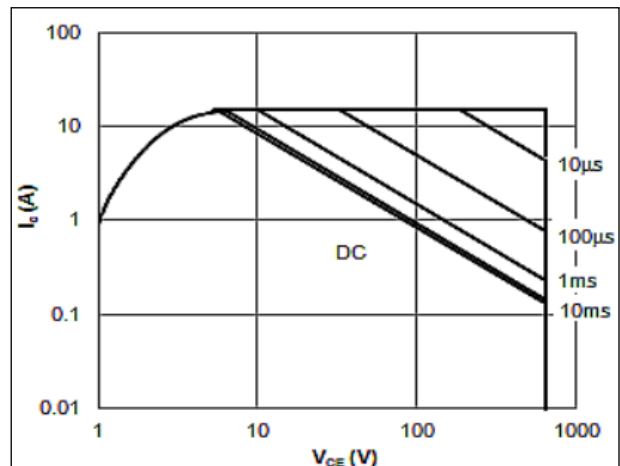
VGE=15V, Ic=5A, Rg=60 Ω



Safe Operating Area For DPAK\IPAK



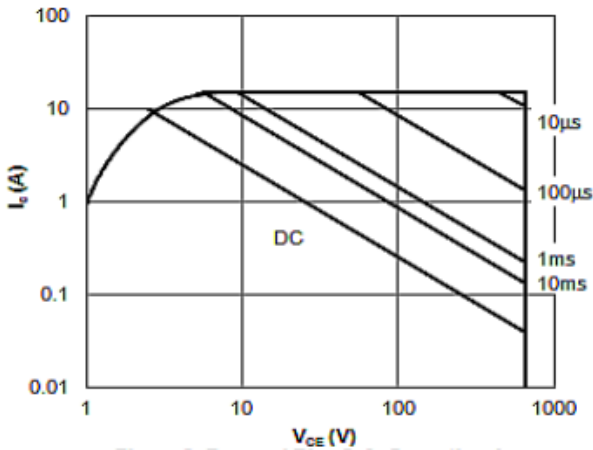
Safe Operating Area For TO-263



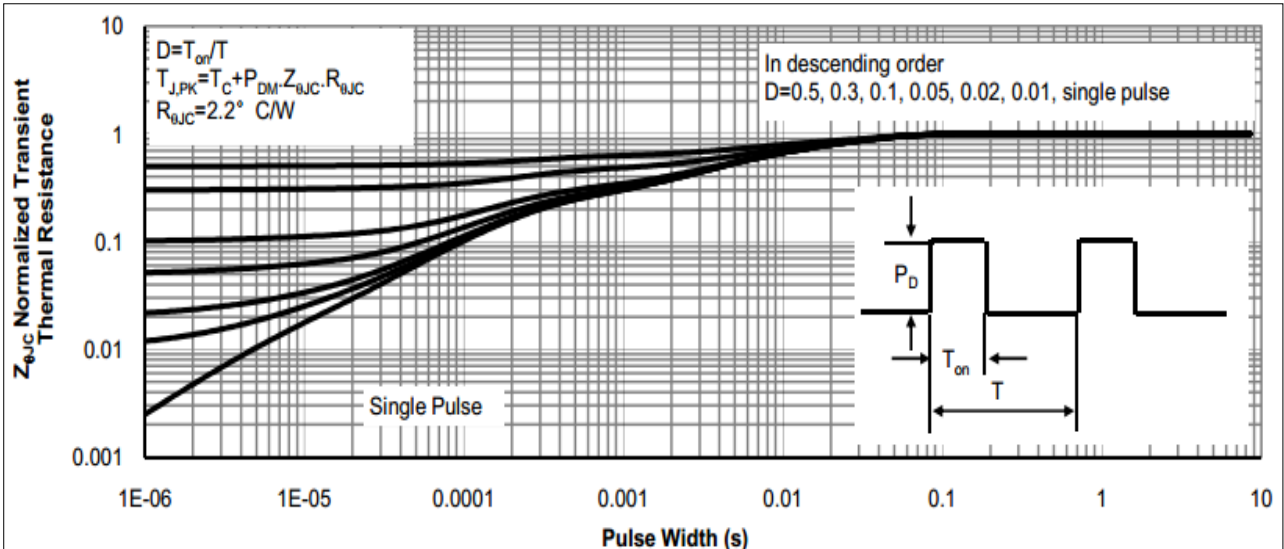




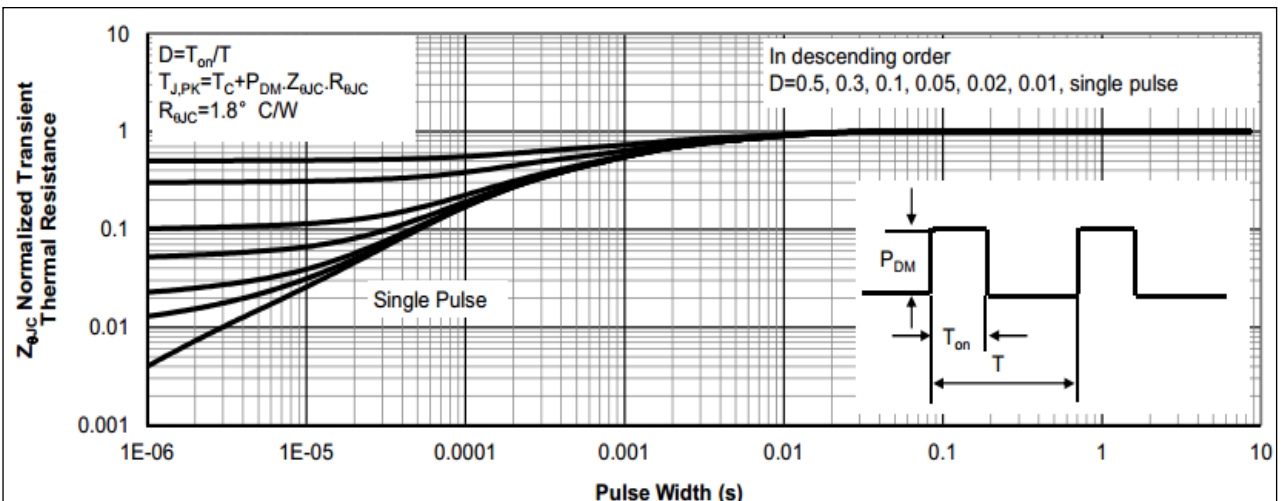
**Safe Operating Area For TO-220MF**



**Normalized Maximum Transient Thermal Impedance for DPAK\IPAK**

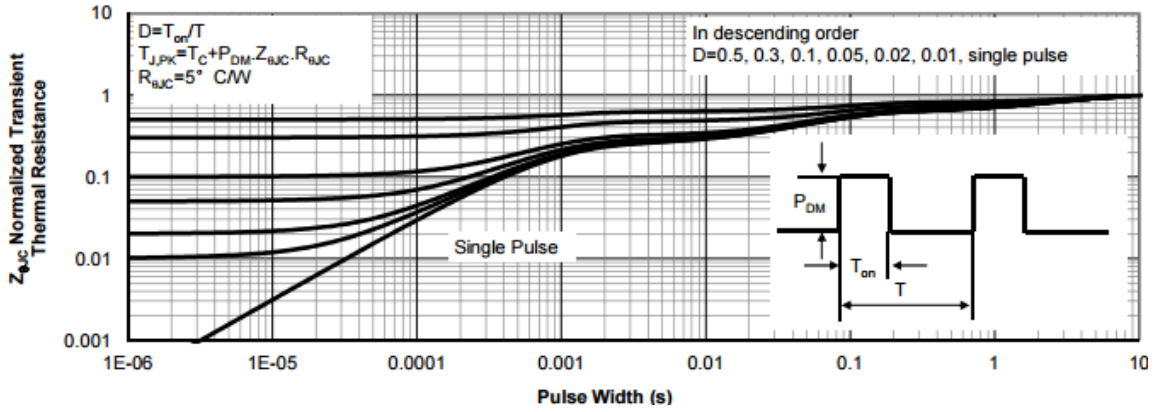


**Normalized Maximum Transient Thermal Impedance for TO-263**





Normalized Maximum Transient Thermal Impedance for TO-220MF

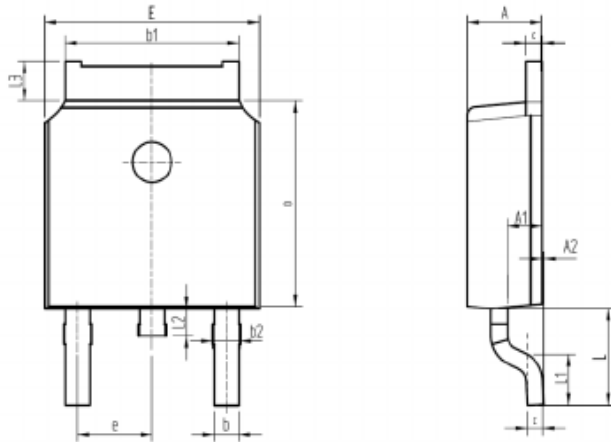




外形尺寸 PACKAGE MECHANICAL DATA

**DPAK**

单位 Unit: mm

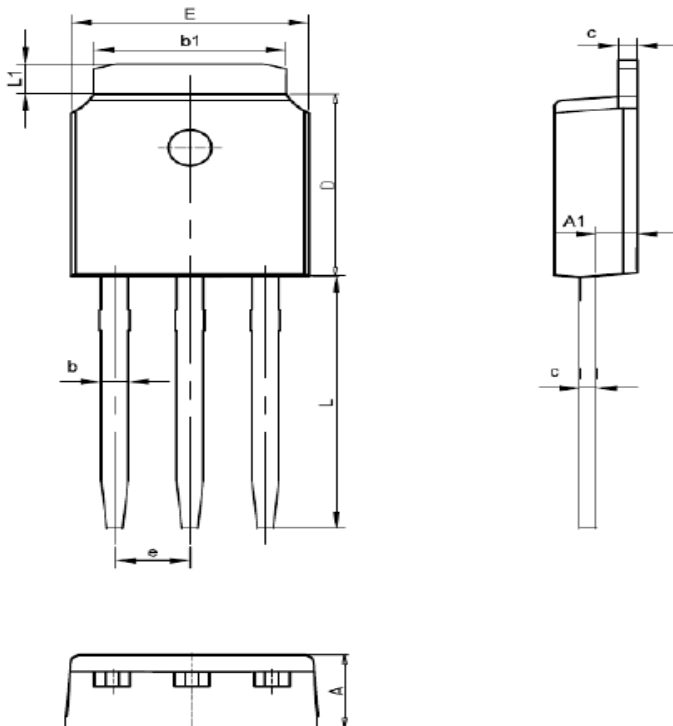


SYMBOL	mm	
	MIN	MAX
A	2.16	2.41
A1	0.97	1.17
A2	0.00	0.15
b	0.63	0.93
b1	5.13	5.53
b2	0.66	0.96
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30

外形尺寸 PACKAGE MECHANICAL DATA

**IPAK**

单位 Unit: mm



SYMBOL	MM	
	MIN	MAX
A	2.1	2.5
A1	0.87	1.27
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
L	9.10	9.70
e	2.286BSC	
L1	0.82	1.22

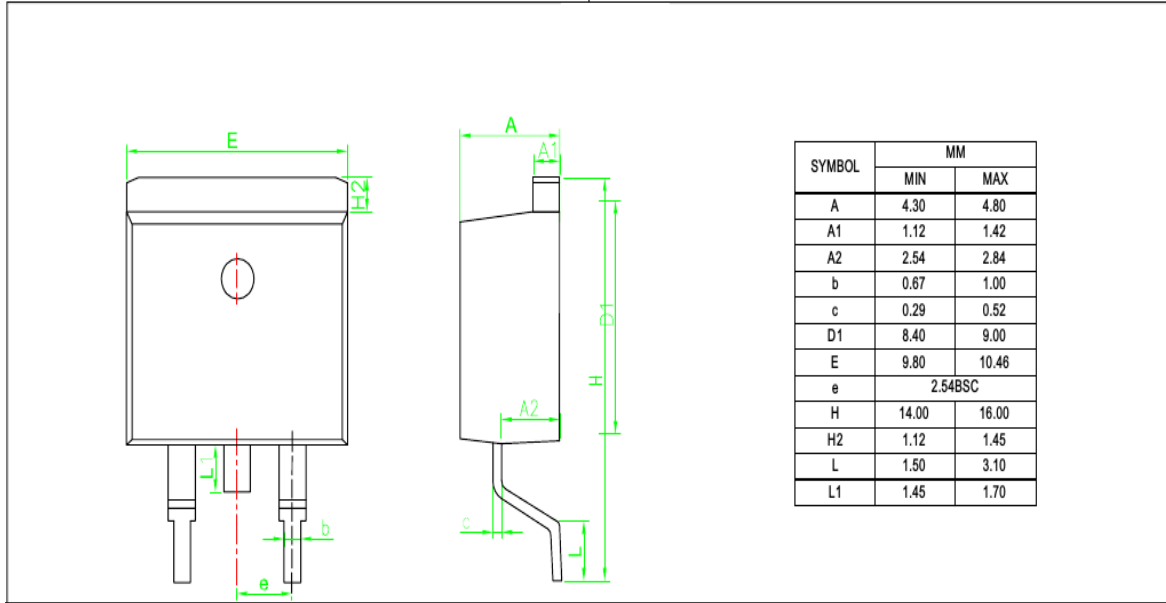




外形尺寸 PACKAGE MECHANICAL DATA

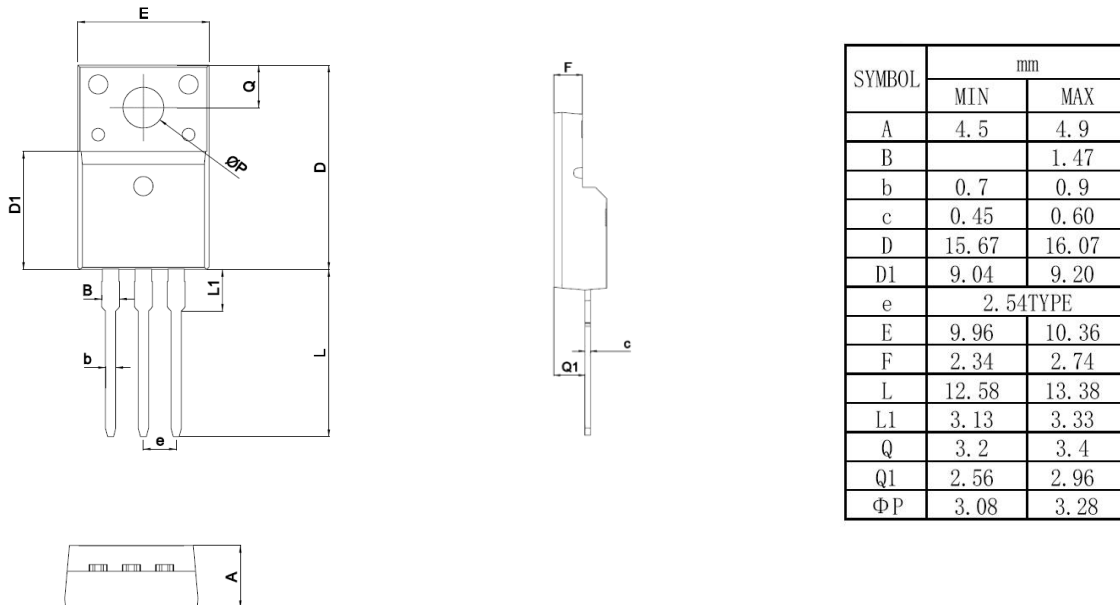
**TO-263**

单位 Unit: mm



**TO-220MF**

单位 Unit: mm





**注意事项**

1. 吉林华微电子股份有限公司的产品销售分为直销和销售代理，无论哪种方式，订货时请与公司核实。
2. 购买时请认清公司商标，如有疑问请与公司本部联系。
3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知

**NOTE**

1. Jilin Sino-microelectronics co., Ltd sales its product either through direct sales or sales agent , thus, for customers, when ordering , please check with our company.
2. We strongly recommend customers check carefully on the trademark when buying our product, if there is any question, please don't be hesitate to contact us.
3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
4. Jilin Sino-microelectronics co., Ltd reserves the right to make changes in this specification sheet and is subject to change without prior notice.

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